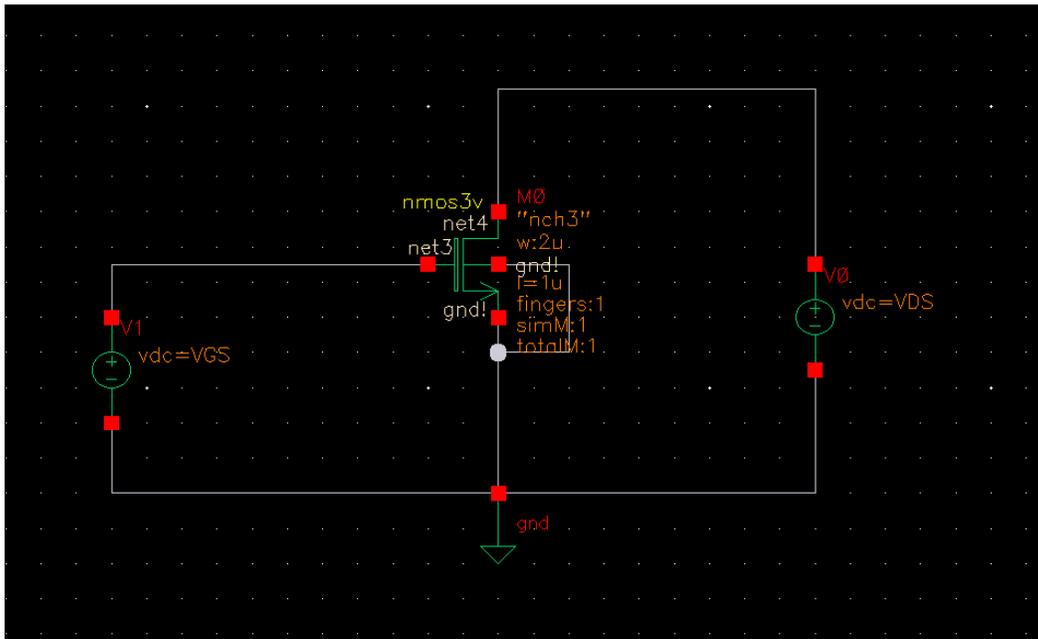


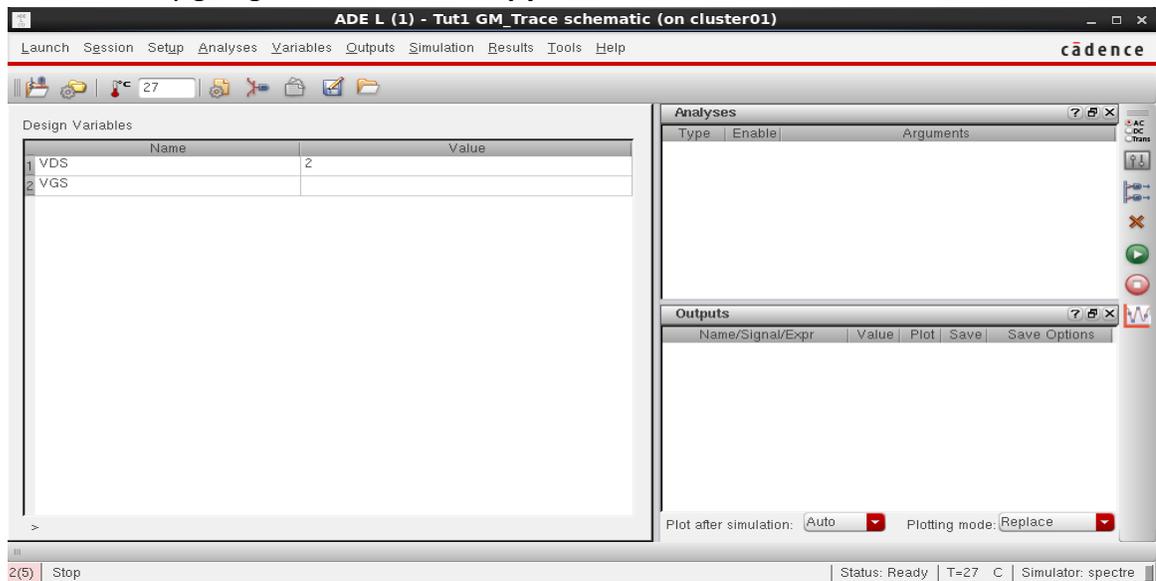
## Plotting gm

Author: Nate Turner

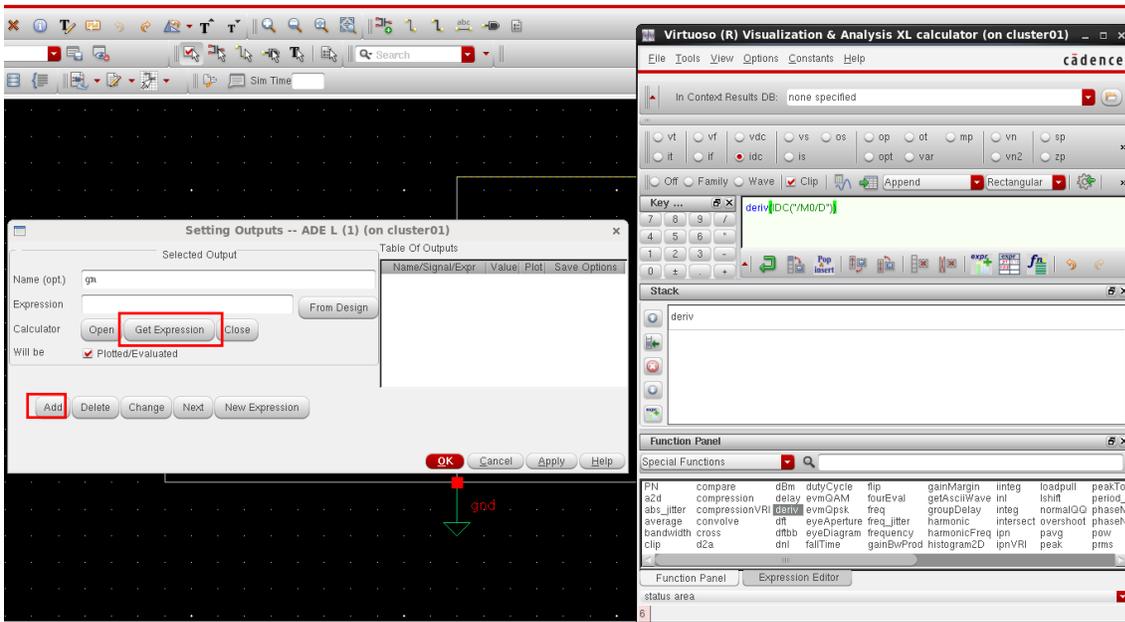
1. Create a schematic as shown in the figure. It should include a nmos3v from the tsmc18 library, with a width of 2u and length of 1u. A drain source voltage of VDS, and a gate source voltage of VGS.



2. Launch ADE L by going to **Launch** → **ADE L**. Copy the design variables from the schematic to the ADE by going to **Variables** → **Copy from Cellview**. Set VDS to 2.



- Go to **Outputs** → **Setup** → type **gm** as the Name. Open the calculator by pressing **Open**. Select **idc** and then click the drain terminal of the MOSFET.  $IDC("/M0/D")$  should appear. From the function panel select **deriv**. The expression in the calculator should match the one in the figure.
- Next from the Setting Outputs window, under calculator select **Get Expression** – shown



in red in the above figure -- this will pull the expression from the calculator to the Expression entry. Then click **Add** → **OK**.

- Next go to **Analyses** → **dc** → **Check Save DC Operating Point** → **OK**
- Go to **Tools** → **Parametric Analysis** and set up the parametric sweep as shown in the figure. Variable: **VGS**, Range Type: **From/To**, From: **0**, To: **3**, Step Mode: **Linear Steps**, Step Size: **0.1**.
- Run the simulation from the parametric analysis window, and you should get a plot that looks similar to the one shown in the figure.

